1. General description

The HEF4014B is a fully synchronous edge-triggered 8-bit static shift register with eight synchronous parallel inputs (D0 to D7), a synchronous serial data input (DS), a synchronous parallel enable input (PE), a LOW-to-HIGH edge-triggered clock input (CP) and buffered parallel outputs from the last three stages (Q5 to Q7).

Operation is synchronous and the device is edge-triggered on the LOW-to-HIGH transition of CP. Each register stage is of a D-type master-slave flip-flop type. When PE is HIGH, data is loaded into the register from D0 to D7 on the LOW-to-HIGH transition of CP. When PE is LOW, data is shifted to the first position from DS, and all the data in the register is shifted one position to the right on the LOW-to-HIGH transition of CP. The clock input's Schmitt trigger action makes it highly tolerant of slower clock rise and fall times.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD} , V_{SS} , or another input.

2. Features and benefits

- Tolerant of slow clock rise and fall times
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from –40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

3. Applications

- Parallel-to-serial converter
- Serial data queueing
- General purpose register

4. Ordering information

Table 1.Ordering information

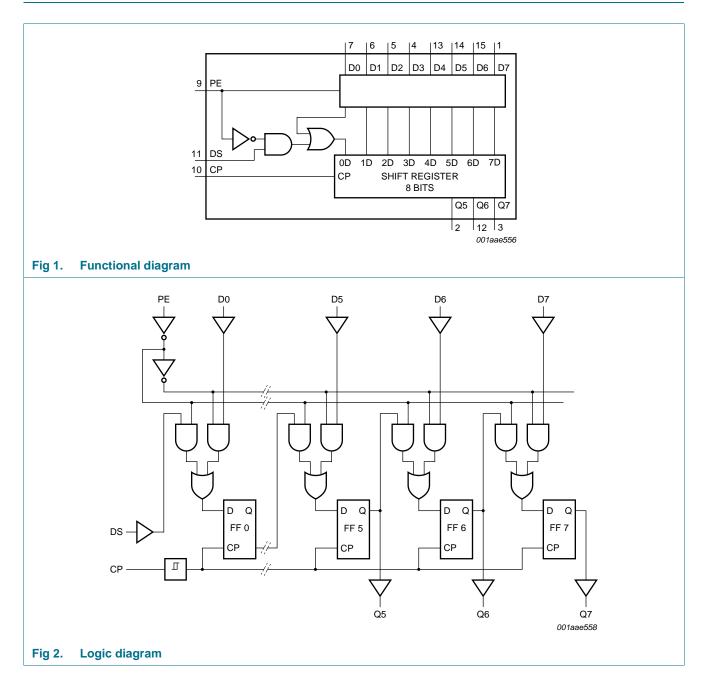
All types operate from -40 °C to +85 °C

Type number	Package		
	Name	Description	Version
HEF4014BP	DIP16	plastic dual in-line package; 16-leads (300 mil)	SOT38-4
HEF4014BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1



8-bit static shift register

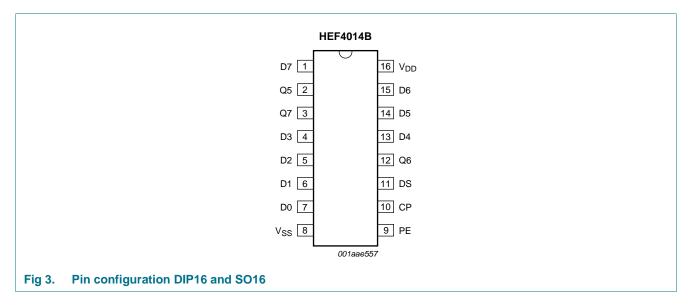
5. Functional diagram



HEF4014B

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
Q5 to Q7	2, 12, 3	output
D0 to D7	7, 6, 5, 4, 13, 14, 15, 1	parallel data input
V _{SS}	8	ground supply voltage
PE	9	parallel enable input
СР	10	clock input (LOW-to-HIGH edge-triggered)
DS	11	serial data input
V _{DD}	16	supply voltage
-		

7. Functional description

Number of clock	Inputs			Outputs		
transitions	СР	DS	PE	Q5	Q6	Q7
Serial operation		l				
1	\uparrow	1D	L	Х	Х	Х
2	\uparrow	2D	L	Х	Х	Х
3	\uparrow	3D	L	Х	Х	Х
6	\uparrow	Х	L	1D	Х	Х
7	\uparrow	Х	L	2D	1D	Х
8	\uparrow	Х	L	3D	2D	1D
	\downarrow	Х	Х	no change	no change	no change
Parallel operation						
1	\uparrow	Х	Н	D5	D6	D7
	\downarrow	Х	Х	no change	no change	no change

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; nD = HIGH or LOW; $\uparrow = LOW$ -to-HIGH clock transition; $\downarrow = HIGH$ -to-LOW clock transition;

8. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{DD} + 0.5 V	-	±10	mA
VI	input voltage		-0.5	V _{DD} + 0.5	V
I _{OK}	output clamping current	$V_{\rm O}$ < –0.5 V or $V_{\rm O}$ > $V_{\rm DD}$ + 0.5 V	-	±10	mA
I _{I/O}	input/output current		-	±10	mA
I _{DD}	supply current		-	50	mA
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +85 \ ^{\circ}C$			
		DIP16 package	<u>[1]</u> _	750	mW
		SO16 package	[2] _	500	mW
Р	power dissipation	per output	-	100	mW

[1] For DIP16 package: Ptot derates linearly with 12 mW/K above 70 °C.

[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

9. Recommended operating conditions

Recommended operating conditions					
Parameter	Conditions	Min	Тур	Max	Unit
supply voltage		3	-	15	V
input voltage		0	-	V_{DD}	V
ambient temperature	in free air	-40	-	+85	°C
input transition rise and fall rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
	V _{DD} = 10 V	-	-	0.5	μs/V
	V _{DD} = 15 V	-	-	0.08	μs/V
	Parameter supply voltage input voltage ambient temperature	ParameterConditionssupply voltageinput voltageambient temperaturein free airinput transition rise and fall rate $V_{DD} = 5 V$ $V_{DD} = 10 V$	ParameterConditionsMinsupply voltage3input voltage0ambient temperaturein free air-40input transition rise and fall rate $V_{DD} = 5 V$ - $V_{DD} = 10 V$ -	ParameterConditionsMinTypsupply voltage3-input voltage0-ambient temperaturein free air-40-input transition rise and fall rate $V_{DD} = 5 V$ $V_{DD} = 10 V$	ParameterConditionsMinTypMaxsupply voltage3-15input voltage0- V_{DD} ambient temperaturein free air-40-+85input transition rise and fall rate $V_{DD} = 5 V$ 3.75 $V_{DD} = 10 V$ 0.5

10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$ V; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V _{DD}	T _{amb} =	-40 °C	T _{amb} = +25 °C		T _{amb} = +85 °C		Unit
				Min	Max	Min	Max	Min	Max	
V _{IH}	HIGH-level input voltage	I _O < 1 μA	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V _{IL}	LOW-level input voltage	$ I_0 < 1 \ \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V _{он}	HIGH-level output voltage	$ I_0 < 1 \ \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V _{OL}	OL LOW-level output voltage	I _O < 1 μA	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level output current	$V_{O} = 2.5 V$	5 V	-	-1.7	-	-1.4	-	-1.1	mA
		$V_{O} = 4.6 V$	5 V	-	-0.52	-	-0.44	-	-0.36	mA
		$V_{O} = 9.5 V$	10 V	-	-1.3	-	-1.1	-	-0.9	mA
		V _O = 13.5 V	15 V	-	-3.6	-	-3.0	-	-2.4	mA
I _{OL}	LOW-level output current	$V_{O} = 0.4 V$	5 V	0.52	-	0.44	-	0.36	-	mA
		$V_{O} = 0.5 V$	10 V	1.3	-	1.1	-	0.9	-	mA
		V _O = 1.5 V	15 V	3.6	-	3.0	-	2.4	-	mA
l	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μA
I _{DD}	supply current	I _O = 0 A	5 V	-	20	-	20	-	150	μA
			10 V	-	40	-	40	-	300	μA
			15 V	-	80	-	80	-	600	μA
CI	input capacitance		-	-	-	-	7.5	-	-	pF

11. Dynamic characteristics

Table 7. Dynamic characteristics

 $T_{amb} = 25 \ ^{\circ}C; V_{SS} = 0 V.$

unio	-) 00 -							
Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula ^[1]	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	CP to Qn;	5 V	103 ns + (0.55 ns/pF)C _L	-	130	260	ns
	propagation delay	see Figure 4	10 V	44 ns + (0.23 ns/pF)C _L	-	55	110	ns
			15 V	32 ns + (0.16 ns/pF)C _L	-	40	80	ns
t _{PLH}	LOW to HIGH	CP to Qn;	5 V	88 ns + (0.55 ns/pF)C _L	-	115	230	ns
	propagation delay	see Figure 4	10 V	39 ns + (0.23 ns/pF)C _L	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF)C _L	-	40	80	ns
t _t	transition time	Qn output;	5 V	2 10 ns + (1.00 ns/pF)CL	-	60	120	ns
		see Figure 4	10 V	9 ns + (0.42 ns/pF)C _L	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C _L	-	20	40	ns
t _W	pulse width	CP input;	5 V		70	35	-	ns
		minimum width;	10 V		30	15	-	ns
		see <u>Figure 5</u>	15 V		24	12	-	ns
t _{su}	set-up time	$PE \rightarrow CP;$	5 V		40	10	-	ns
		see <u>Figure 5</u>	10 V		25	5	-	ns
			15 V		15	0	-	ns
	$DS \rightarrow CP;$	5 V		+35	-5	-	ns	
		see <u>Figure 5</u>	10 V		+25	-5	-	ns
			15 V		25	0	-	ns
		$Dn \rightarrow CP;$	5 V		+35	-5	-	ns
		see Figure 5	10 V		+25	-5	-	ns
			15 V		25	0	-	ns
t _h	hold time	$PE \rightarrow CP;$	5 V		+25	-5	-	ns
		see Figure 5	10 V		20	0	-	ns
			15 V		15	0	-	ns
		$DS \rightarrow CP;$	5 V		30	15	-	ns
	see Figure 5	10 V		20	10	-	ns	
		15 V		15	7	-	ns	
	$Dn \rightarrow CP;$	5 V		30	15	-	ns	
	see Figure 5	10 V		20	10	-	ns	
			15 V		15	7	-	ns
f _{clk(max)}	maximum clock	see Figure 5	5 V		6	13	-	MHz
	frequency		10 V		15	30	-	MHz
			15 V		20	40	-	MHz

[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).

[2] t_t is the same as t_{THL} and t_{TLH} .

HEF4014B Product data sheet

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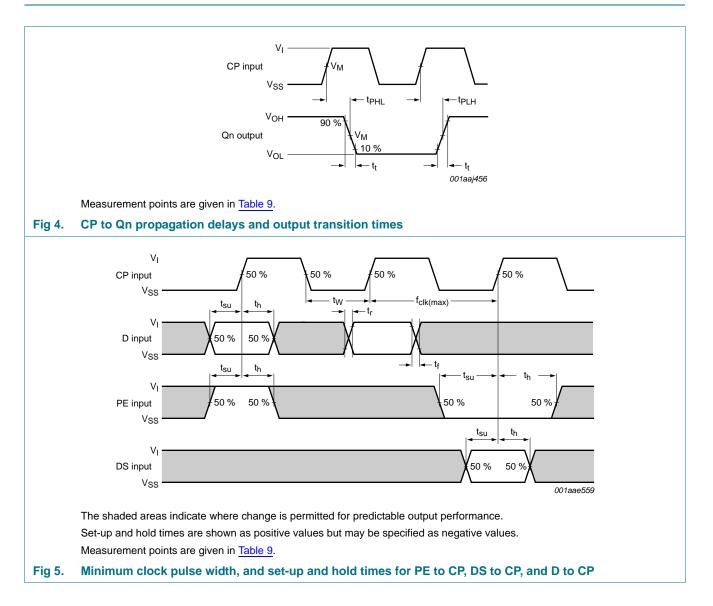
8-bit static shift register

 $\Sigma(C_L \times f_o) = sum of the outputs.$

	calculated from the		shown. $V_{SS} = 0$ V; $t_r = t_f \le 20$ ns; $T_{amb} = 25$	5 °C.
Symbol	Parameter	V_{DD}	Typical formula for P_D (μ W)	Where:
PD	dynamic power	5 V	$P_D = 900 \times f_i + \Sigma(f_o \times C_L) \times V_DD^2$	f_i = input frequency in MHz;
	dissipation	10 V	$P_D = 4300 \times f_i + \Sigma (f_o \times C_L) \times V_DD{}^2$	f_o = output frequency in MHz;
		15 V	$P_D = 12000 \times f_i + \Sigma(f_o \times C_L) \times V_DD^2$	C_L = output load capacitance in pF; V_{DD} = supply voltage in V;

Table 8. Dynamic power dissipation P_D

12. Waveforms



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Table 9. Measurement points		
Supply voltage	Input	Output
V _{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}
		,
Test data is given in <u>Table 10;</u>		
Definitions for test circuit:		
DUT = Device Under Test.		
C_L = load capacitance including jig	and probe capacitance.	
R_T = termination resistance should	be equal to the output impedance Z_{o} of the pu	lse generator.
Fig 6. Test circuit		

Table 10. Test data

Supply voltage	Input		y voltage Input Load		Load
V _{DD}	VI	t _r , t _f	CL		
5 V to 15 V	V _{SS} or V _{DD}	≤ 20 ns	50 pF		

8-bit static shift register

13. Package outline

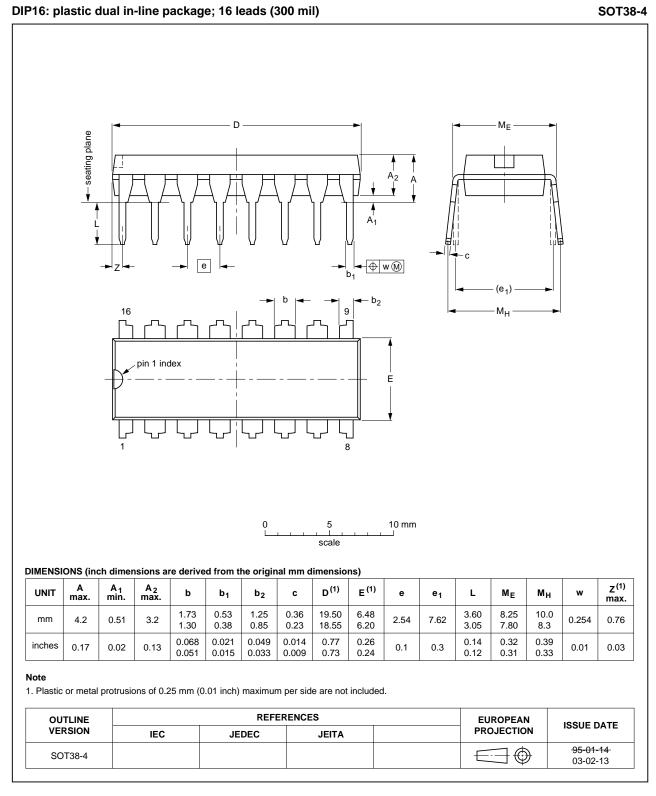


Fig 7. Package outline SOT38-4 (DIP16)

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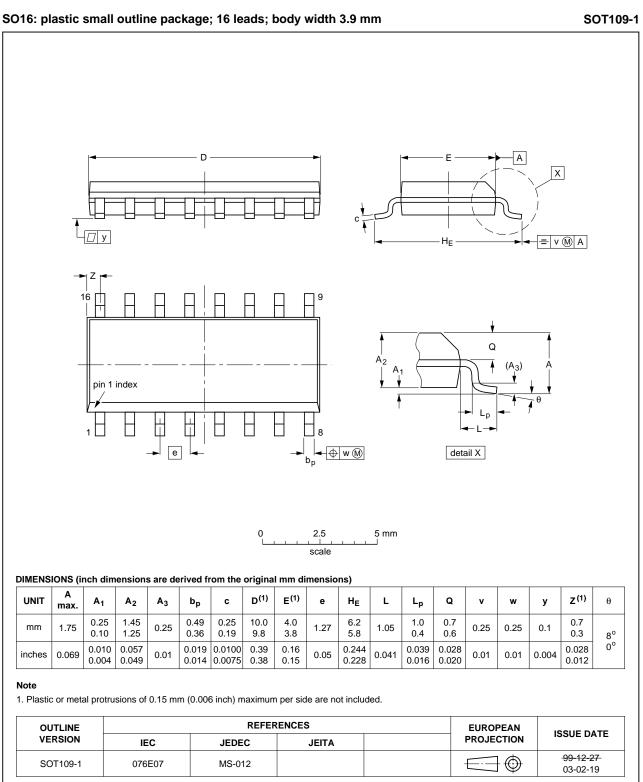


Fig 8. Package outline SOT109-1 (SO16)

HEF4014B

14. Revision history

Table 11. Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4014B v.8	20111121	Product data sheet	-	HEF4014B v.7
Modifications:	 Legal pages 	s updated.		
	 Changes in 	"General description" and "	Features and benefits".	
HEF4014B v.7	20110914	Product data sheet	-	HEF4014B v.6
HEF4014B v.6	20091102	Product data sheet	-	HEF4014B v.5
HEF4014B v.5	20090624	Product data sheet	-	HEF4014B v.4
HEF4014B v.4	20090122	Product data sheet	-	HEF4014B_CNV v.3
HEF4014B_CNV v.3	19950101	Product specification	-	HEF4014B_CNV v.2
HEF4014B_CNV v.2	19950101	Product specification	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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